

## NEMI Lead Free Solder Efforts

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*Mark Kwoka Intersil Corp.*



# NEMI Lead Free Solder Efforts

- Tin Whisker Accelerated Test Task Group
- Tin Whisker User Group
- Tin Whisker Modeling Group
- Lead Free Assembly and Rework
- Lead Free Assembly – Completed
- RoHS Transition Task Group (new)
- Lead Free Wave Soldering (new)

[www.nemi.org](http://www.nemi.org)



# Whisker Test Standardization ECTC 2004

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*Nhat (Nick) Vo*



# Whisker Test Standardization Committee

***Objective: to develop industry standard test methods for predicting tin whiskers***

## ***Committee Structure***

- Nick Vo (Chair) – Motorola/Freescale
- Jack McCullen (Co-Chair) – Intel
- Mark Kwoka (Co-Chair) – Intersil
- 48 companies including three governmental organizations

***An open program (non-NEMI members welcome)***





# Whisker Test Standardization Team





# Whisker Test Standardization Status

## Status:

- Phase 1 evaluation: Identify accelerated whisker test methods by evaluating various known test methods; **completed**
- Phase 2 evaluation: A factorial experiment looking for test methods involving Temperature, Humidity, and Thermal cycling; **completed**
- Submitted proposed test methods based on Phase 2 results, and inputs from JEITA and ITRI to JEDEC for survey ballot
- Phase 3 evaluation: Confirm Phase 2 results, determine whisker growth saturation to possibly define end points and assess mitigation techniques; **underway**
- Phase 4 evaluation: Verify voltage bias effects; just starting - boards and samples are being collected
- Phase 5 evaluation: Assess proposed test methods to other isothermal and thermal cycle conditions and possibly correlate to use condition





## Phase 1 Evaluation Summary

- **Samples (brass coupons and 8 lead SOICs) were prepared with bright Sn along with SnPb (control)**
- **Whiskers formed only on the bright Sn-plated coupons, and were few in number - much less than expected**
- **There were two possible explanations of low whiskering**
  - the level of impurities and/or contamination were maintained very low (samples plated in the lab) and thus helped to retard whisker growth
  - when the terminations were formed the plating cracked reducing stress in the finish and thus helped to retard whisker growth
- **The results of the Phase 1 study were inconclusive**



## Phase 2 Evaluation Parameters

- Finishes
  - Matte pure tin plated from **MSA and Sulfate** baths
  - 90Sn/10Pb alloy as a control
- Plating done on **production line** and in laboratory
- Samples
  - Production type components (OLIN 194 Cu SOIC)
  - Brass coupons (flat)
- Test Conditions (modified conditions from Phase 1)
  - **Ambient** exposure ( 30 C) for 5 months
  - Temperature + humidity storage (**30C/90RH** & **60C/95RH**) for 4 weeks
  - Thermal cycling (500 cycles; **-55C to 85C**, 20 min cycle with 7 min dwell)
  - And a **combination of all of the above** conditions





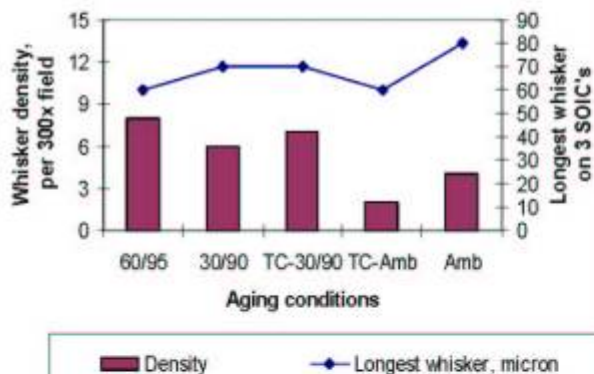
## Samples Tested in Phase 2 Evaluation

- A: 2 to 3 $\mu$ m, Matte Sn (Sulphate) on OLIN194 Cu SOIC molded/singulated
- B: 10 to 12 $\mu$ m, Matte Sn (Sulphate) on OLIN194 Cu SOIC molded/singulated
- C: 2 to 3 $\mu$ m, Bright Sn on brass coupon
- D: 10 to 12 $\mu$ m, 90Sn/10Pb on OLIN194 Cu SOIC molded/singulated (control)
- E: 2 to 3 $\mu$ m, Matte Sn (MSA) on OLIN194 Cu SOIC molded/singulated
- F: 10 to 12 $\mu$ m, Matte Sn (MSA) on OLIN194 Cu SOIC molded/singulated

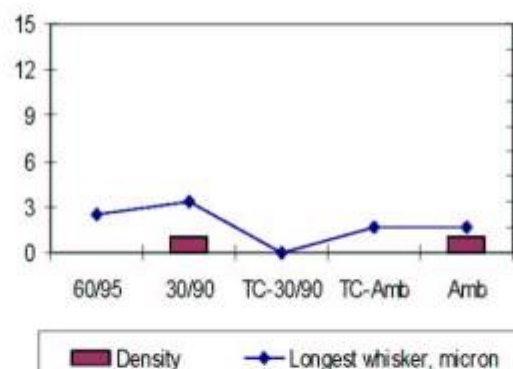


## Phase 2: Effect of Bath Chemistry

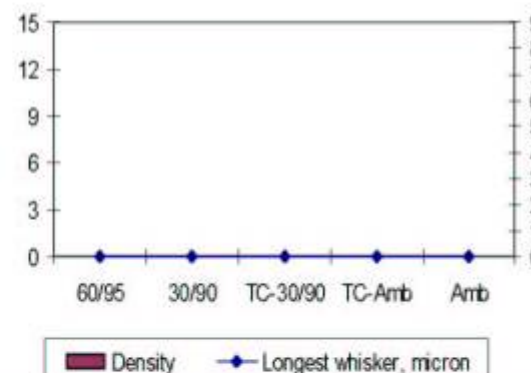
Thin MSA Supplier A



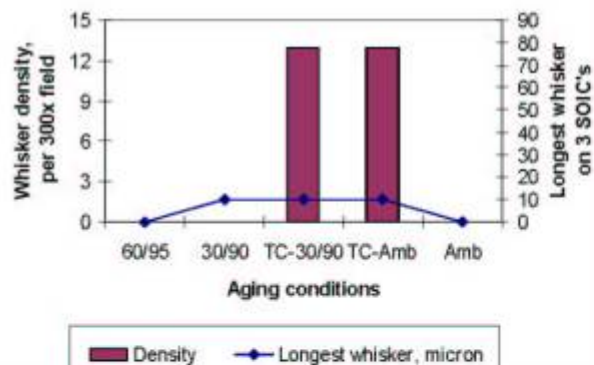
Thin MSA Supplier B



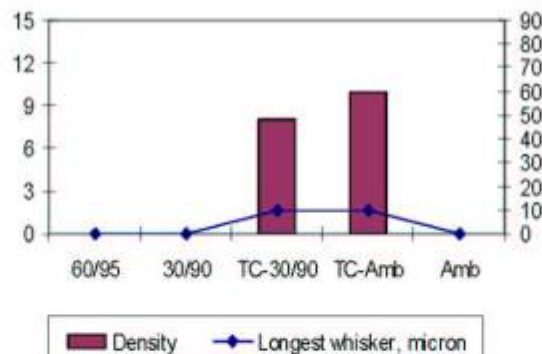
Thin Sulfate



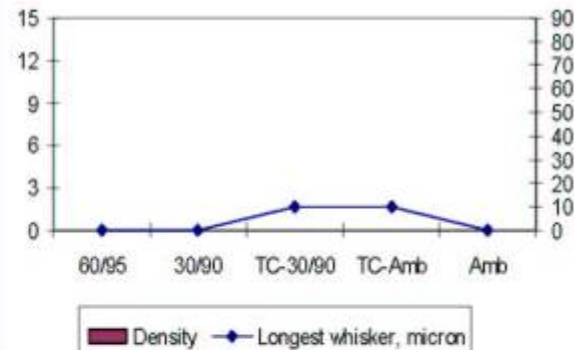
Thick MSA Supplier A



Thick MSA Supplier B



Thick Sulfate





## Phase 2 Evaluation Summary

- In general, more whiskers grew with the -55C/85C temperature cycle method, followed by 60C/90%RH storage; some whisker growth was also observed with the ambient environment
- There is no indication in this experiment that thicker deposits are less prone to whisker
- Bath chemistry/plating process parameters seem to have the most significant influence on whiskering
  - Slight advantage of sulfate-based chemistry comparing to a good-practice MSA bath
  - Significant difference between two MSA-based processes from two suppliers
- Whisker growth may be a multi-factorial phenomenon and the theory/model describing will need take into consideration numerous parameters





## Recommended Test Method

***Prepared whisker test method for release by JEDEC.***

### ***Purpose:***

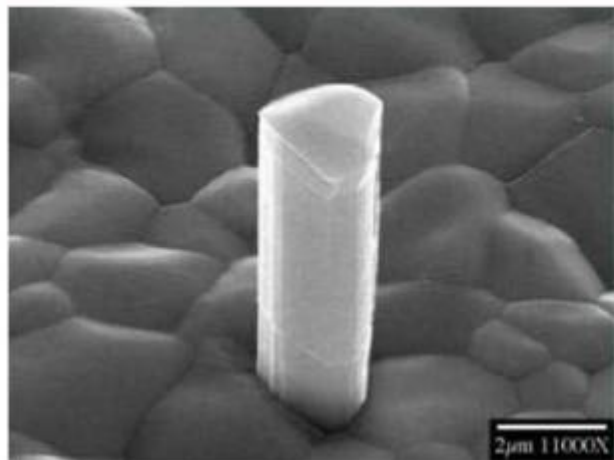
- Provide test method to aid in the evaluation and development of plating finishes.
- Provide an industry-standardized test for comparison of whisker-propensity for different plating systems and processes.
- Not intended for use in reliability assessment or qualification.



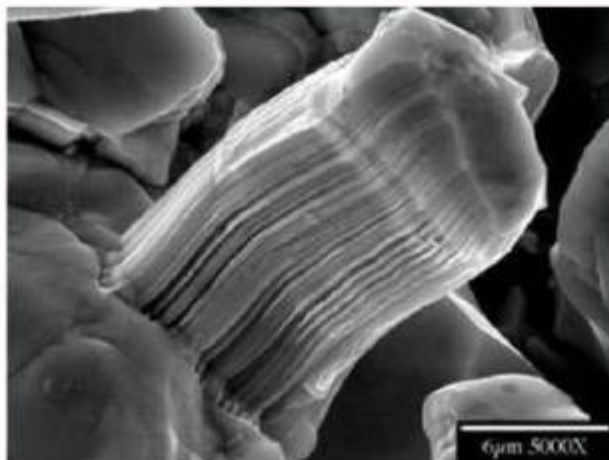
### ***Recommended Test Methods:***

- **-55°C (+0, -10) / 85°C (+10, -0) air-air temperature cycle (20minutes/cycle)**
- **60 + 5 °C, 93 +2, -3 % RH**
- **20 - 25 °C, ~30-80% RH**
- **All three tests are to be performed using separate samples**
- **Each test condition is to be performed independently**
- **Arrived at methods in collaboration with JEITA and ITRI**

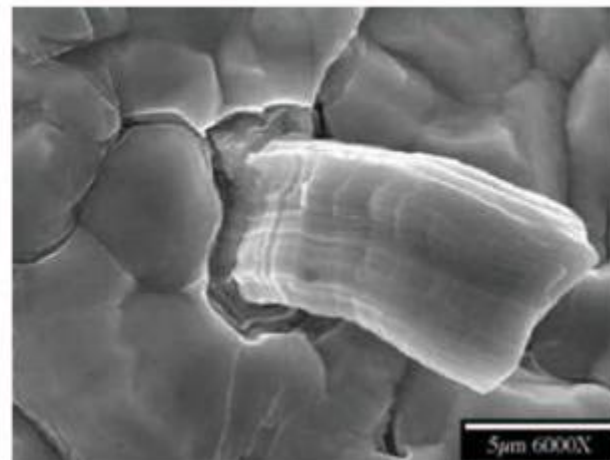
# Whisker Examples



**Consistent cross-section  
(column)**



**Striations**



**Rings**





## Phase 3 Evaluation – Validate & Verify

### Tests:

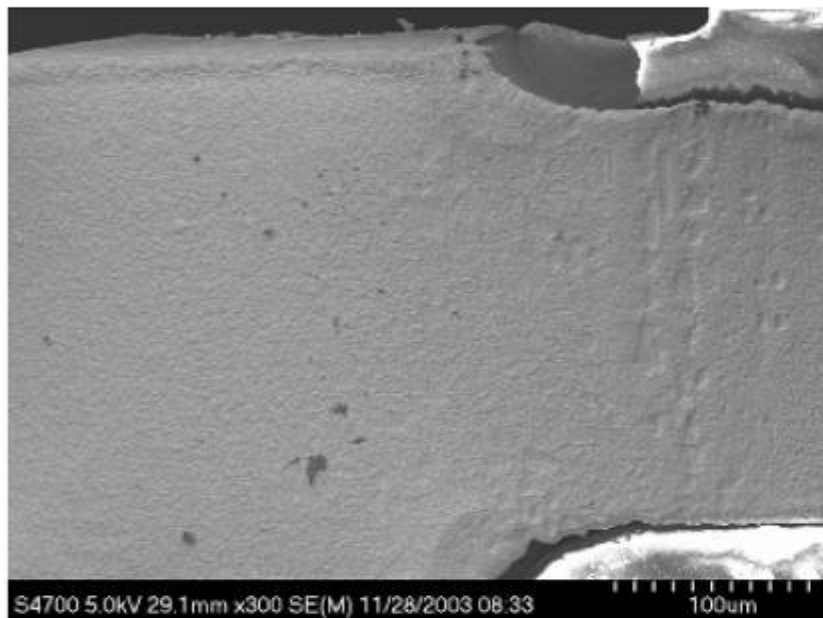
- **-55°C (+0, -10) / 85°C (+10, -0) air-air temperature cycle** (20minutes/cycle) up to 3000 cycles (500 cycles check points)
- **60°C, 93±5%RH temperature / humidity storage** 9000 hrs (~1 year) with 1000 hr check points
- **Ambient storage (~23°C, ~60%RH)** up to 18000 hours (~2 years) with 1000 hr check points

### Samples:

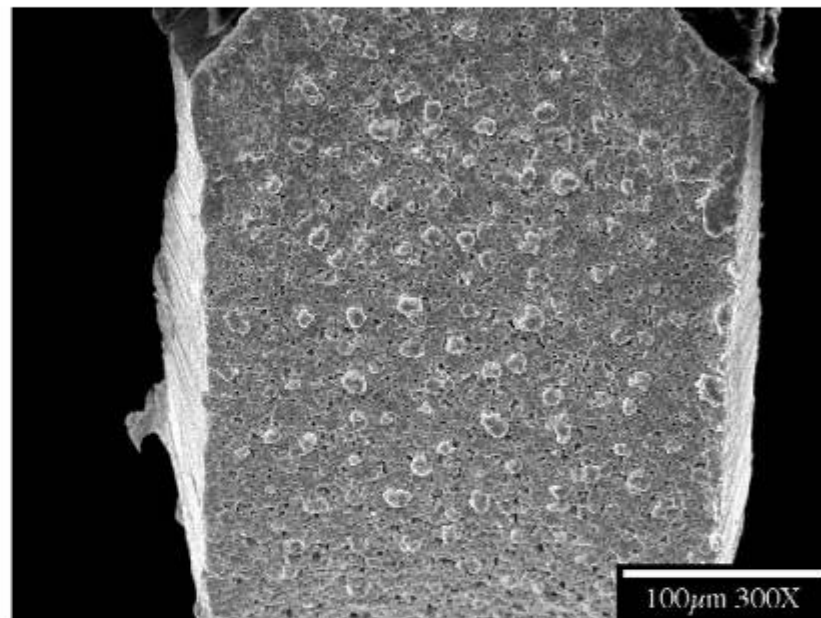
- Leaded packages from **production assembly sites**
- Sn, SnBi, SnCu and SnAg finishes
- SnPb as control
- Copper CDA194, copper C7025 and Alloy42 leadframes
- For comparison include cells with
  - » Matte Ni underplating
  - » Fused (confirm melting) Sn
  - » Post-plate baked Sn
  - » Hot-dipped Sn
  - » JEITA test vehicle



## Phase 3 - SnPb Post-3000cyc SEM



Cell 2, Sn/Pb,  $t_0$  uncycled.

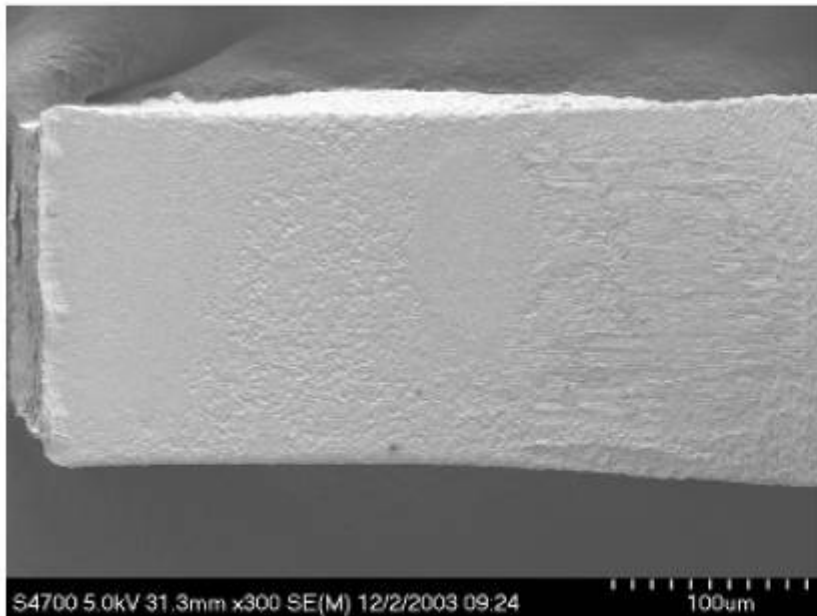


Cell 2, Sn/Pb, 3000 cycles.

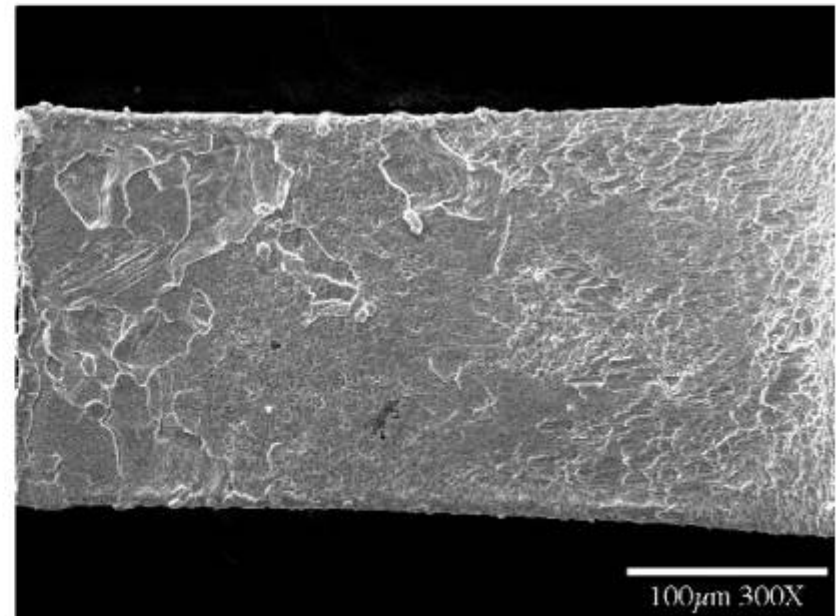
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## Phase 3 - Matte Sn 3-5 $\mu$ m Post-3000cyc SEM



Cell 4, Matte Sn 3-5 $\mu$ m,  $t_0$  uncycled.

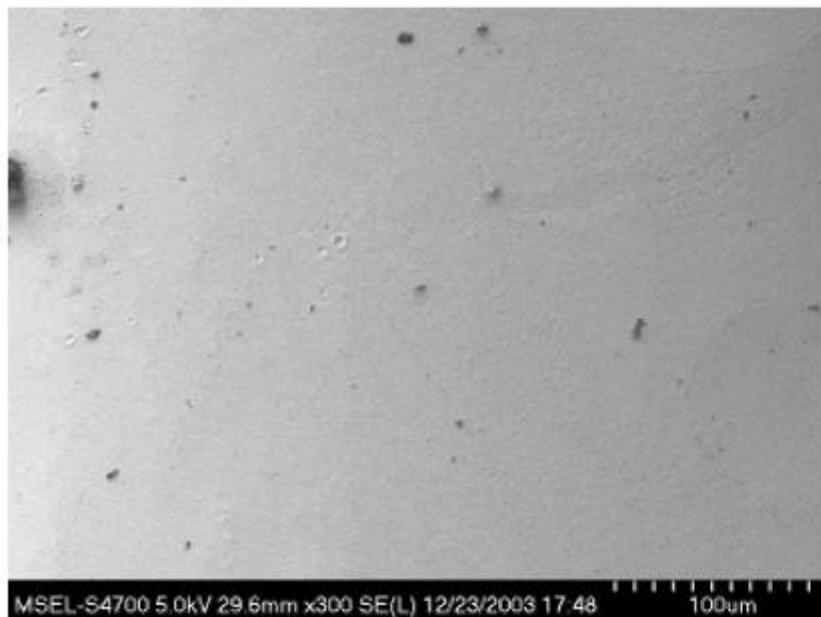


Cell 4, Matte Sn 3-5 $\mu$ m, 3000 cycles.

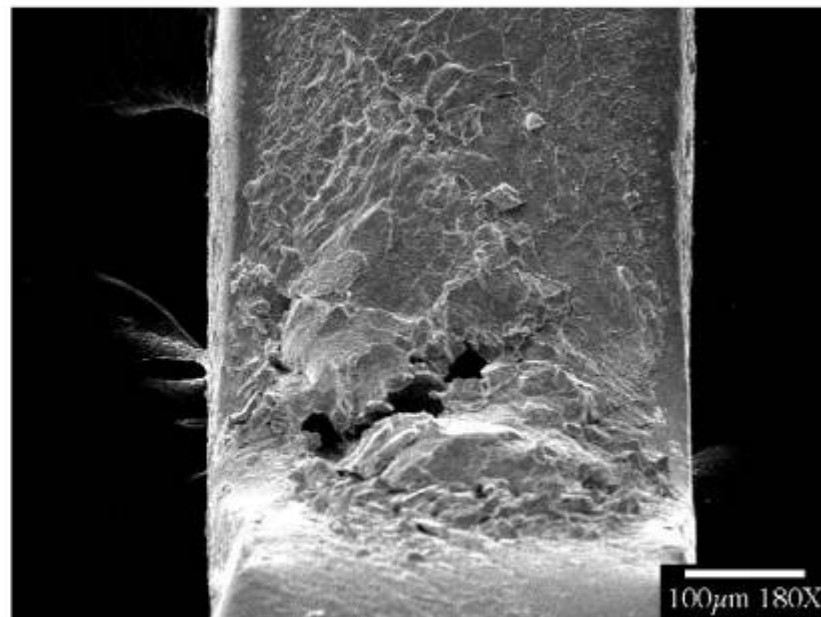




## Phase 3 – Hot-dipped Sn Post-3000cyc SEM



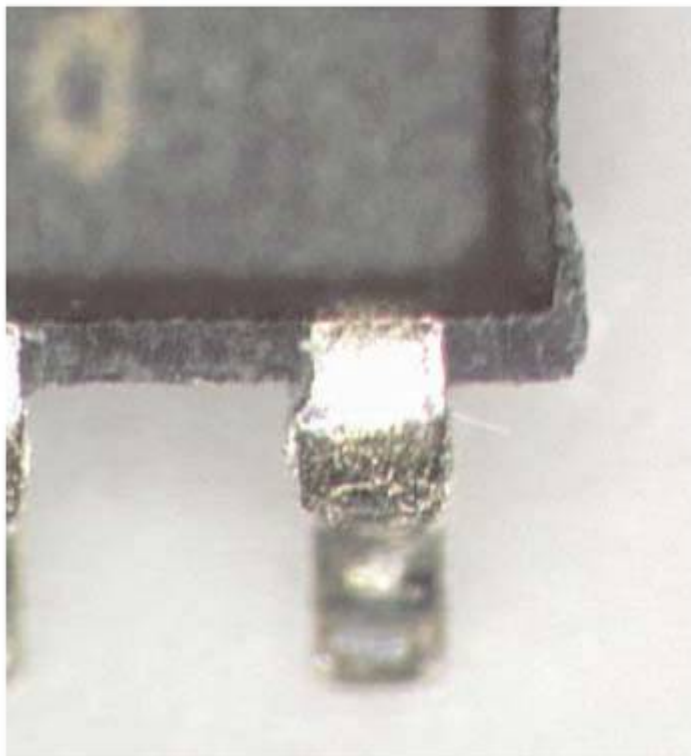
Cell 10, Hot Dipped Sn,  $t_0$  uncycled.



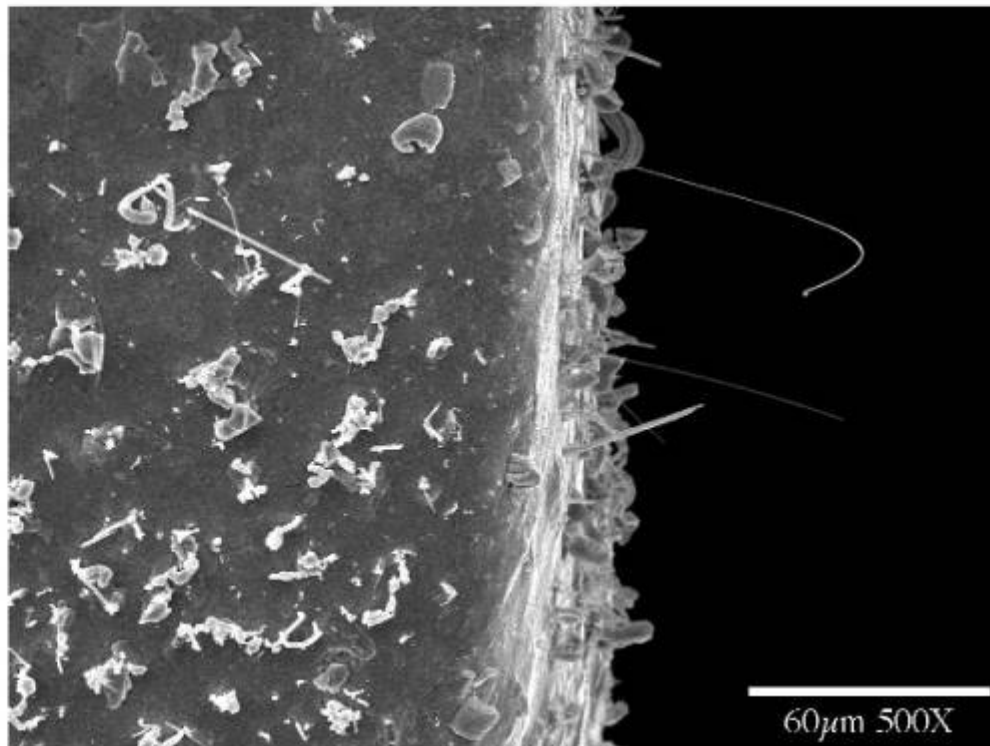
Cell 10, Hot Dipped Sn, 3000 cycles.



## Phase 3 – Hot-dipped Sn Post-3000cyc SEM



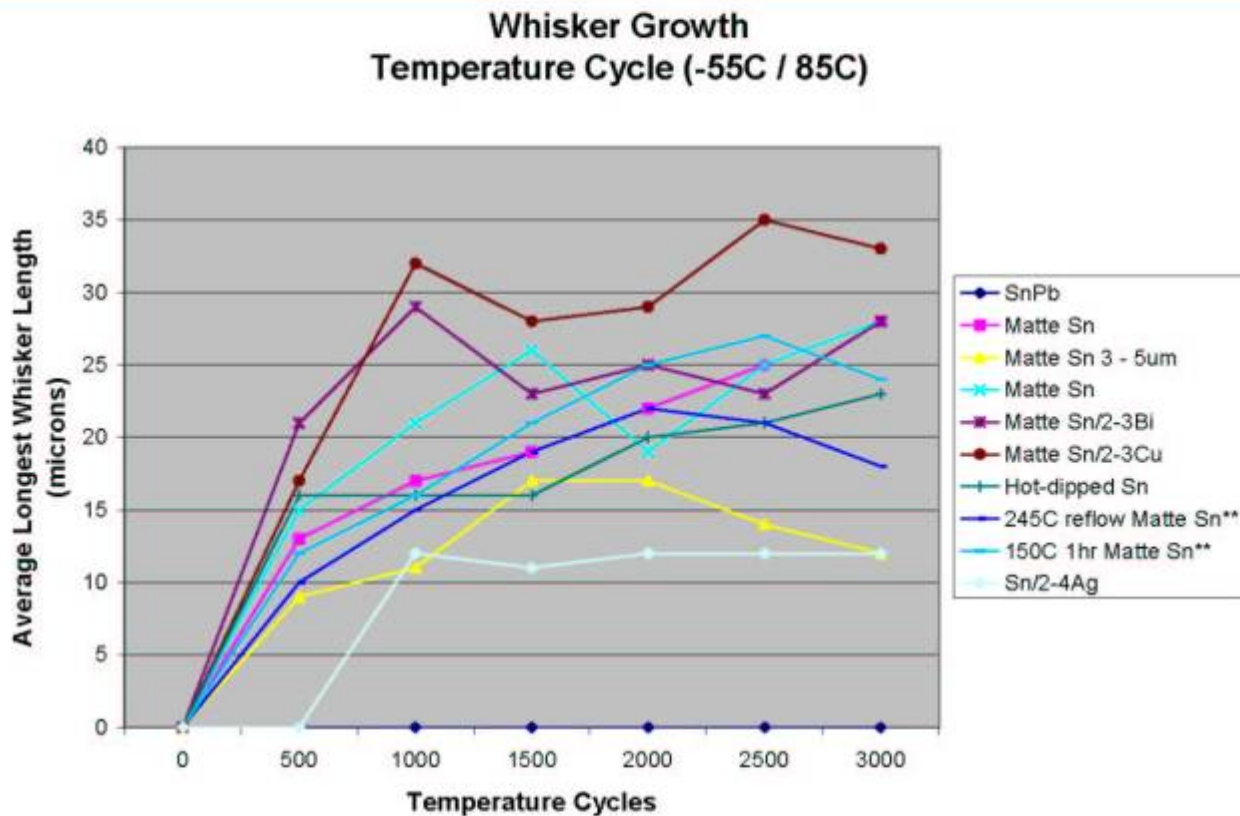
Cell 10 Hot Dipped Sn  
Optical image



Cell 10 Hot Dipped Sn same lead as at left.



## Phase 3 - Thermal Cycle Results



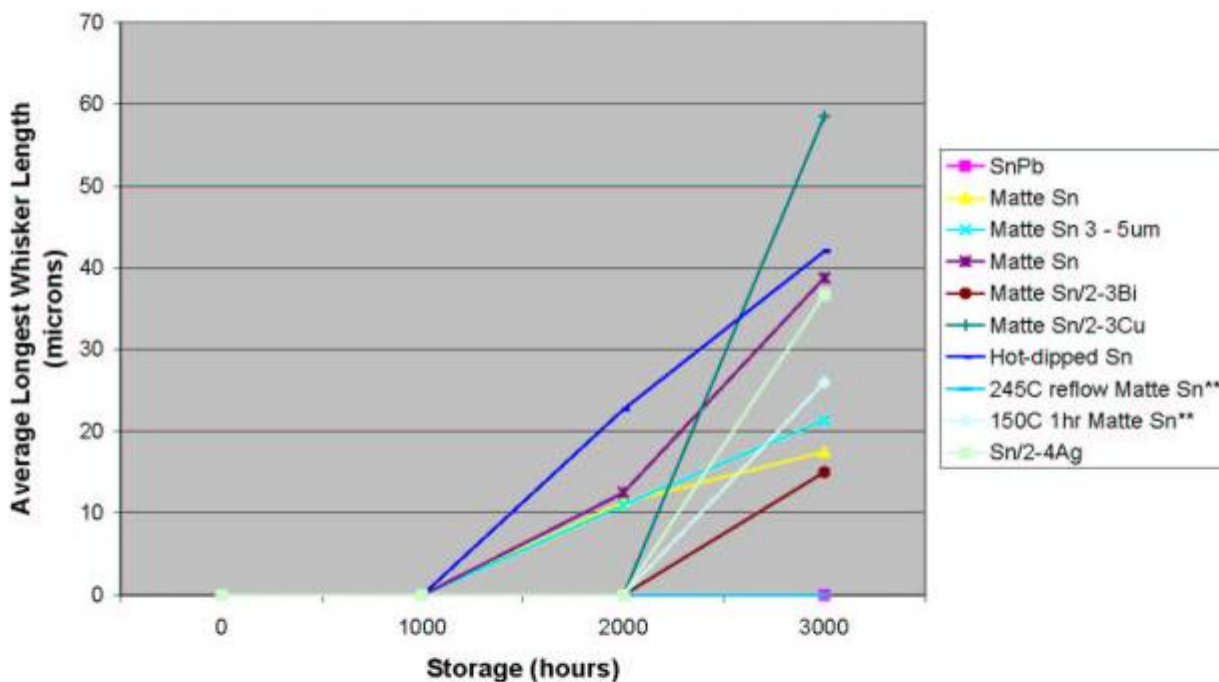
- Whiskers formed as soon as 500cycles
- Between 1000 and 1500 cycles whisker growth appears to saturate
- Grain growth and coarsening is easily observable at 3000cycles





## Phase 3 – Isothermal Storage Results

Whisker Growth  
Temperature/Humidity Storage (60C / 95RH)



- Whiskers formed as soon as 2000hours
- Different incubation periods for each finish
- Corrosion products is observed at 3000hours for some cells
- Not all leads whisker (such as the case with SnAg)

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## Phase 3 – Summary

- ***Test methods are showing repeatability***
- ***Thermal cycle whisker growth appears to saturate around 1500cycles***
- ***Component construction effects longest whisker length observed in thermal cycle testing***
- ***Additional analysis on-going for thermal cycle data***
- ***Incubation period is different for different plating types in isothermal storage***
- ***Plating finishes respond differently between test methods (150C baked Sn, SnAg samples)***
- ***Isothermal and ambient storage is on-going***



# **NEMI Tin Whisker User Group**

**Tin Whisker Acceptance Test Requirements  
(Updated July 28, 2004)**

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*Joe Smetana, Alcatel, Chairman*





## The NEMI Tin Whisker User Group Active Participants

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**Participant companies provide products in Automotive, Consumer, High-End Computing, Space, & Telecom Industries**

- |  |                             |
|--|-----------------------------|
| • Joe Smetana                            | Alcatel - Chairman          |
| • Rick Charbonneau                       | Formerly of Storage Tek     |
| • Vicki Chin, Zequn Mei, Diana Chiang    | Cisco                       |
| • Richard Coyle                          | Lucent - Co-Chairman        |
| • George Galyon                          | IBM eSystems Group          |
| • Ron Gedney                             | NEMI consultant             |
| • Bob Hilty                              | Tyco Electronics            |
| • John Lau                               | Agilent Technologies        |
| • Sean McDermott                         | Celestica                   |
| • Rich Parker                            | Delphi Electronics & Safety |
| • Frances Planinsek                      | Storage Tek                 |
| • Heidi Reynolds & David Love            | Sun Microsystems            |
| • Valeska Schroeder, Elizabeth Bennedeto | Hewlett Packard             |

**Also**

**Nick Vo of Freescale represents the supplier point of view**

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## Tin Whisker Mitigation Requirements

- **Components qualified and accepted by this testing shall utilize one of the preferred mitigation practices specified in “Tin Whiskers, NEMI Users Group Position statement” (available at [www.nemi.org](http://www.nemi.org)), briefly summarized:**
  - Fusing by the component supplier of the tin plating within a short time frame after plating.
  - Use of a hot dip tin (or tin alloy) finish rather than plating.
    - » Hot dip SnAgCu is the preferred alloy.
  - Use of nickel plated barrier layer between the base material and the tin
  - Annealing/heat treating (150°C for 1 hour) of a matte tin finish within a short time frame after plating (typically less than 24 hours).
    - » Note: This mitigation practice may not be acceptable to all users.
  - Other acceptable mitigation practice as defined by the User Group Position Statement section III, paragraph 15



## Overview of Testing

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- **3 Test Segments: 2 isothermal and 1 Temperature Cycling of NEMI “Tin Whisker Growth Test” (Submitted to JEDEC)**
  - Ambient/Storage (30°C, 60% RH)–minimum\* 4000 Hrs
  - Aging/Temperature & Humidity (60°C, 93%RH)–minimum\* 4000 Hrs
  - Thermal Cycling (-55°C to + 85°C)–minimum\* 1000 cycles

\* Test Durations may be longer depending on results (more later)
- **Tests are extended to include assembly preconditioning and bias to represent actual use conditions**





## Sample Size – Test Components

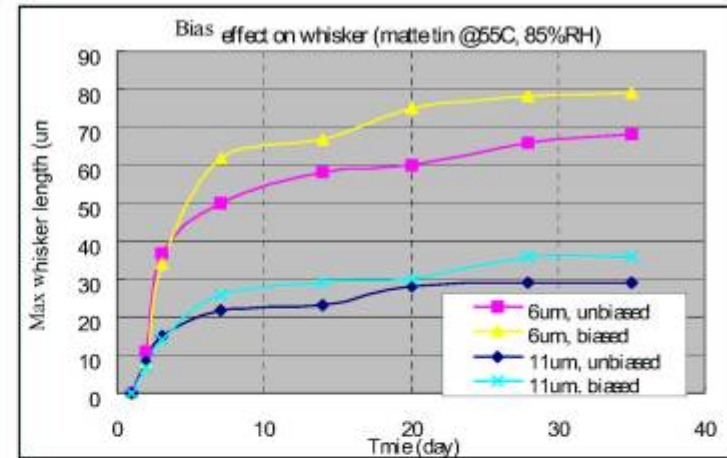
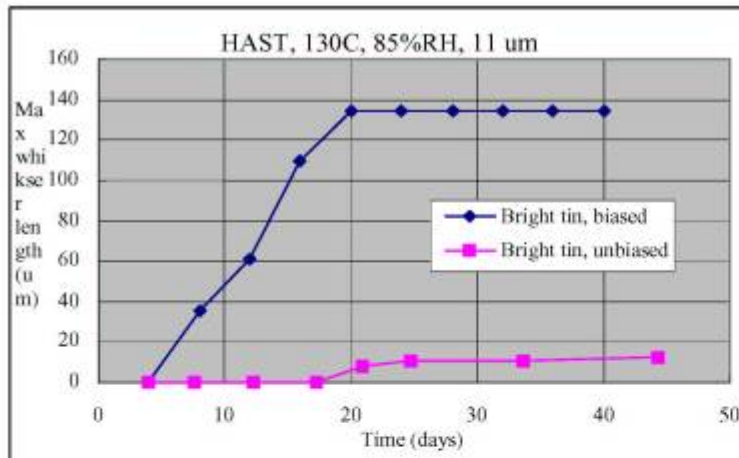
Each lot - a different date code & plated at least one week apart

# Components (leads)/Lot (minimum) <sup>(1)</sup>	# Lots	Precondition <sup>(3)</sup>	Test Condition	Total # Components (leads) (minimum)
3 (30)	3	4 weeks @ room temperature (RT)	Storage – No Bias	9 (90)
3 (30)	3	4 weeks RT	Aging – No Bias	9 (90)
3 (30)	3	4 weeks RT, then Assembly Sim @ 215°C	Storage – No Bias	9 (90) <sup>(3)</sup>
3 (30)	3	4 weeks RT, then Reflow @ 255°C	Storage – No Bias	9 (90) <sup>(3)</sup>
3 (30)	3	4 weeks RT, then Assembly Sim @ 215°C	Aging – No Bias	9 (90) <sup>(3)</sup>
3 (30)	3	4 weeks RT, then Reflow @ 255°C	Aging – No Bias	9 (90) <sup>(3)</sup>
3 (30)	3	4 weeks RT, then Assembly Sim @ 215°C	Thermal Cycle – No Bias	9 (90)
3 (30)	3	4 weeks RT, then Reflow @ 255°C	Thermal Cycle – No Bias	9 (90) <sup>(3)</sup>
3 (30)	3	4 weeks RT, then Assembly @ 215°C	Storage – Bias	9 (90) <sup>(2) (3) (4)</sup>
			Total Components Required	<b>81 (810)</b>



## Bias Testing

- **Bias effect on Tin Whisker Growth appears to be finish dependent**
  - Our primary goal is to test whether or not whisker growth on the finish being qualified is affected by bias or not.
  - As such we've limited the testing to ambient samples only.
  - Examples: #1 Phillips data

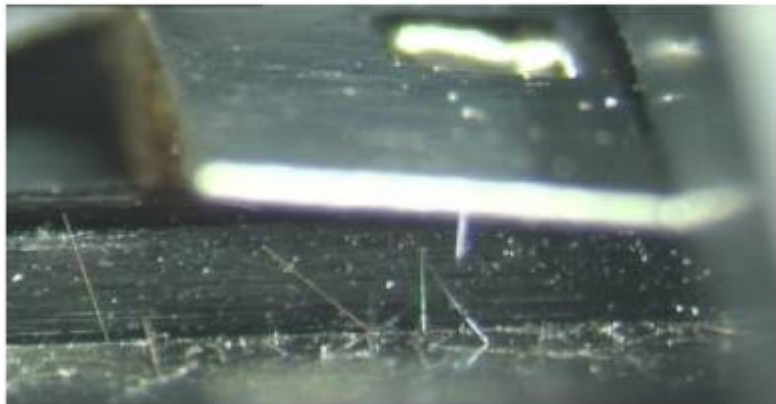


Clear effect on Bright Tin, Matte Tin Data not conclusive  
(Philips statement: "no effect")

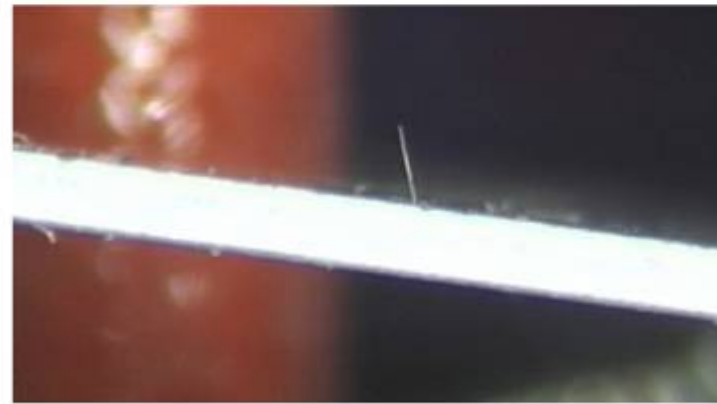


## Bias Testing (continued)

- **Example 2: TI Application Report SZZA037 - January 2003 (Tests on Matte Tin)**
  - “we found whiskers quite consistently on the biased samples, but not on the parallel run of parts with no bias”
- **Example 3: Alcatel Field Failure on Bright Tin Plated Breaker (50V Bias) (Tin should have been reflowed – but was not)**



Whiskers in Bias Area – Dense and 2-5 mm long!



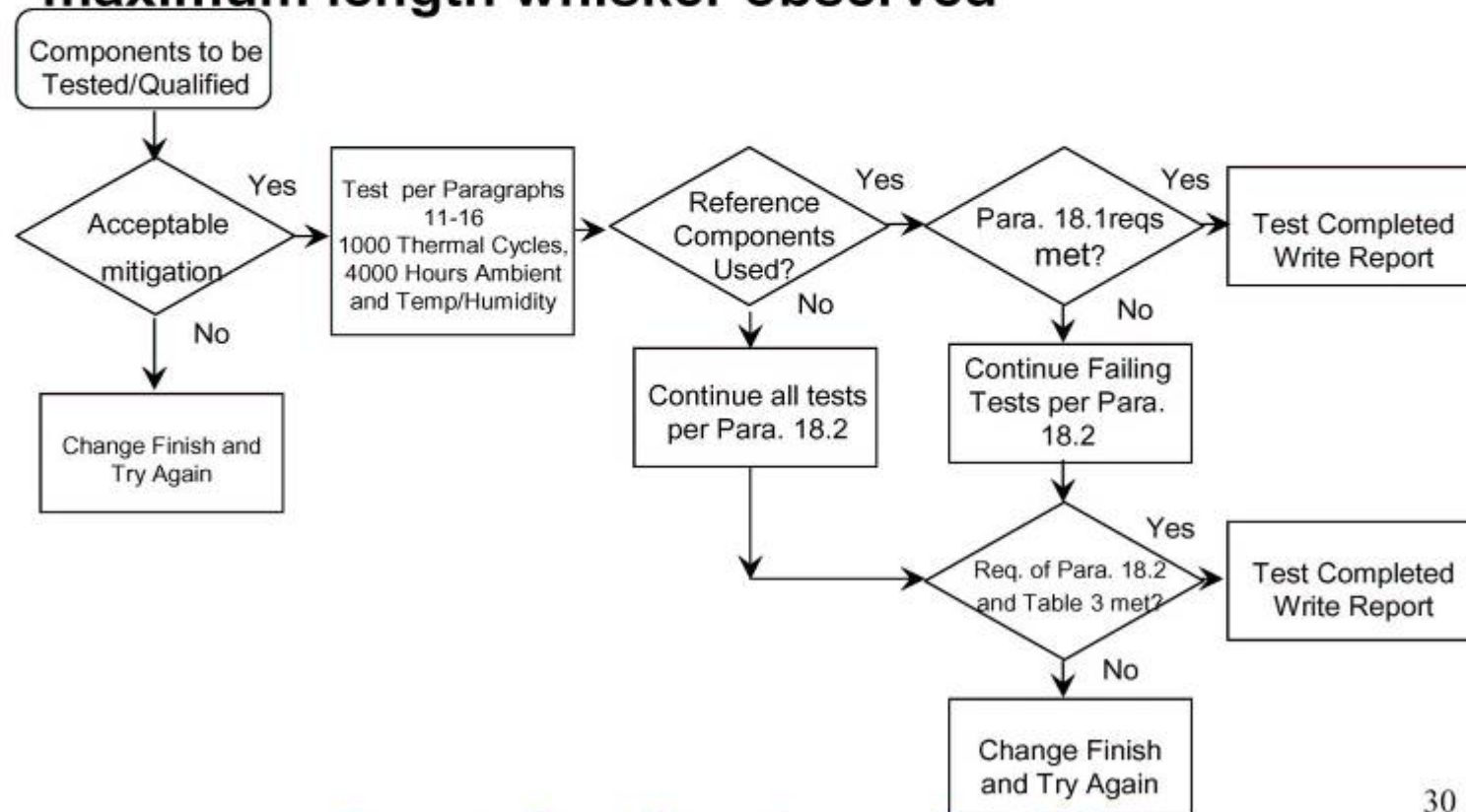
Whiskers away from Bias Area – Much Fewer and a max of about 1mm long





## Acceptance Requirements

- Whisker acceptance requirements are based on the maximum length whisker observed**





## Acceptance Requirements (continued)

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- **Tested Finish after 1000 T/C, 4000 Hours Storage (Ambient), 4000 Hours Aging (Temp/Humidity)**
  - Whisker Length = SnPb Reference (or better)
    - » Done – Tests pass
  - If any tests fail to = SnPb Reference or if SnPb Reference components not used, must be continued (failing tests only)
    - » T/C test – minimum of 2000 cycles or 3 consecutive measurements at 500 cycle intervals show no growth
    - » Storage and/or Aging test – minimum of 5000 hours or 3 consecutive measurements at 1000 hour intervals show no growth
      - If you can't inspect the same whiskers – increase the sample sizes to show statistical significance!
    - » Must meet the Maximum Whisker Length Requirements - following

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## Max Length Without a Short Circuit

- **Worst case, this is equal to  $\frac{1}{2}$  the distance from a lead to another lead or lead on another component or 1X the distance to the nearest trace on the PCB.**

– An excerpt from the Appendix B table:

Device Pitch	Typical Minimum gap between leads <sup>(1)</sup>	Maximum allowable whisker length in application (=1/2 min typical gap)	Maximum allowable whisker length in testing (safety factor = 2/3 maximum distance)	Maximum allowable whisker length in testing (safety factor = $\frac{1}{2}$ maximum distance)
Discrete Device (2 pin)	200 $\mu\text{m}$	100 $\mu\text{m}$	67 $\mu\text{m}$	50 $\mu\text{m}$
0.65 mm to < 1.27 mm	150-200 $\mu\text{m}$ <sup>(2)</sup> (JEDEC MS-204)	75 – 100 $\mu\text{m}$	51 – 67 $\mu\text{m}$	38-50 $\mu\text{m}$
0.5mm to < 0.65 mm	125–150 $\mu\text{m}$ <sup>(2)</sup> (JEDEC MS-204)	63 -75 $\mu\text{m}$	42-51 $\mu\text{m}$	32-38 $\mu\text{m}$
0.4mm to < 0.5mm	120 $\mu\text{m}$ <sup>(2)</sup> (JEDEC MO-194B)	60 $\mu\text{m}$	40 $\mu\text{m}$	30 $\mu\text{m}$

**Below our requirements...**

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## Class Definitions

- **The company purchasing components will classify its products.** Below are general guidelines for product classes. However, these guidelines may not apply in all cases.
  - **Class 1**
    - » **Mission/Life Critical High Reliability Applications** such as military, space and medical applications
      - Pure tin and high tin content alloys not acceptable
  - **Class 2**
    - » **High Reliability Business Applications** such as Telecom Infrastructure equipment, High-end Servers, etc.
      - Long product lifetimes and minimal downtime
      - Products such as disc drives typically fall into this category
      - Breaking off of a tin-whisker is a concern
  - **Class 3**
    - » **Consumer Products**
      - Short product lifetimes.
      - No major concerns with tin whiskers breaking off



## Whisker Length Limits

Maximum Whisker Length			
Device Considerations (Package type, lead pitch or operating frequency)	Class 1	Class 2	Class 3
<b>Discrete Device (2 pins)</b>	Pure tin and high tin content alloys not acceptable.	40 $\mu\text{m}$	67 $\mu\text{m}$ <sup>(1)</sup>
<b>Multi-lead packages</b>			(Minimum gap between leads - .05mm)/3 or 67 $\mu\text{m}$ , whichever is smaller <sup>(1)(2)(3)</sup>
<b>Operating Frequency &gt; 6GHz (RF)<sup>(4)</sup> or <math>t_{\text{rise}} &lt; 59</math> psec (digital)</b>			50 $\mu\text{m}$

- (1) Often must also meet high frequency/high speed requirements
- (2) Spacing does not account for dam bar protrusion, a risk area
- (3) Accounts for up to 0.05mm bent leads. Max of 67 $\mu\text{m}$  accounts for adjacent discrete devices.
- (4) Degradation associated with tin whiskers increases with frequency. The maximum frequency analyzed was 20GHz.



## Safety Factor

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- **Based on all the previous, the User Group chose the following safety factors for test data relative to field data**
  - **Class 3: Maximum allowed whisker =  $\frac{2}{3}$  Worst case situation**
  - **Class 2: Maximum allowed whisker =  $\frac{1}{2}$  Worst case situation**
    - » **Note – rounded up from 37.5 to 40 $\mu$ m for  $\frac{1}{2}$  RF concerns**
    - » **Also compromised on 0.4 mm pitch devices**





## Process Controls and Periodic Testing

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- **We are convinced that repeatability of the process is one of the key items that affect tin whisker propensity of a finish**
  - Suppliers must define and maintain plating process controls
  - Some specifics that Users require
    - » Carbon content shall be kept below 0.05%
    - » Copper content (except for SnCu alloys) should be kept below 0.5%
  - Characteristics of the tin plating shall also be determined and controlled



## Ongoing Tin Whisker Monitoring

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- **Supplier will establish a system to periodically monitor the performance of the processes for whisker generation. The specifics of this system are left to the supplier however the following minimum guidelines are suggested.**
  - A representative sample of components should be taken for each designated time period
  - The time period for these samples should be at least monthly
  - The storage conditions for these components should include a relative humidity of 60% or greater. Using the ambient test conditions of reference 3.2 (Tin Whisker Test) is preferred.
  - The samples should be inspected for whiskers 6 months from the date of plating.
  - Results should be compared to baseline measurements. If these are exceeded, supplier should take appropriate corrective actions.